## **MOSEL-VITELIC**

## MS62256A 32K x 8 HIGH SPEED CMOS STATIC RAM

#### Features

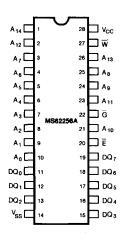
- High-speed 20/25/35 ns
- Low Power dissipation: MS62256A 900mW (Typ.) Operating 50mW (Typ.) Standby
- Fully static operation
- All inputs and outputs directly TTL compatible
- Three state outputs
- Ultra low data retention supply current at V<sub>CC</sub> = 2V

#### Description

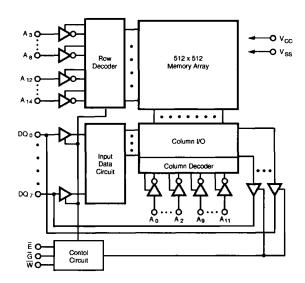
The MS62256A is a 262,144-bit static random access memory organized as 32,768 words by 8 bits and operates from a single 5 volt supply. It is built with MOSEL-VITELIC's high performance twin tub CMOS process. Inputs and three-state outputs are TTL compatible and allow for direct interfacing with common system bus structures. The MS62256A is available in the following standard 28-pin packages:

300 MIL Plastic DIP 300 MIL Small Outline J-Bend (SOJ)

### Pin Configurations



### Functional Block Diagram



#### Pin Descriptions

#### A<sub>0</sub> - A<sub>14</sub> Address Inputs

These 15 address inputs select one of the 32768 8-bit words in the RAM.

## E Chip Enable Input

Ē is active LOW. The chip enable must be active to read from or write to the device. If it is not active, the device is deselected and is in a standby power mode. The DQ pins will be in the high-impedance state when deselected.

#### G Output Enable Input

The output enable input is active LOW. If the output enable is active while the chip is selected and the write enable is inactive, data will be present on the DQ pins and they will be enabled. The  $\overline{DQ}$  pins will be in the high impedance state when  $\overline{G}$  is inactive.

#### Truth Table

Mode	Ē	G	W	I/O Operation
Standby	Н	Х	Х	High Z
Read	L	L	Н	D <sub>OUT</sub>
Output Disabled	L	н	H	High Z
Write	L	Х	L	D <sub>IN</sub>

## Absolute Maximum Ratings (1)

		<i>-</i>		
Symbol	Parameter		Rating	Units
V <sub>CC</sub>	Supply Voltage		-0.3 to 7	
V <sub>IN</sub>	Input Voltage		-0.3 to 7	٧
V <sub>DQ</sub>	Input/Output Voltage	Applied	-0.3 to 6	
T <sub>BIAS</sub>	Temperature Under Bias	Plastic	-10 to +125	ů
T <sub>STG</sub>	Storage Temperature	Plastic	-40 to +150	ပ္
$P_D$	Power Dissipation		1.0	w
lout	DC Output Current		50	mA

 Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability and degrade performance characteristics.

### Write Enable Input

The write enable input is active LOW and controls read and write operations. With the chip enabled, when  $\overline{W}$  is HIGH and  $\overline{G}$  is LOW, output data will be present at the DQ pins; when  $\overline{W}$  is LOW, the data present on the DQ pins will be written into the selected memory location.

### DQ<sub>0</sub> - DQ<sub>7</sub> Data Input/Output Ports

These 8 bidirectional ports are used to read data from or write data into the RAM.

V<sub>CC</sub> Power Supply

VSS Ground

### **Operating Range**

Range	Ambient Temperature	V <sub>oc</sub>
Commercial	0°C to +70°C	5V ± 10%

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### DC Electrical Characteristics (over the commercial operating range)

Parameter			N	<b>AS62256</b>	A	
Name	Parameter	Test Conditions	Min.	Typ.(1)	Max.	Units
	Guaranteed Input Low Voltage(2,3)		-0.3	-	0.8	٧
V <sub>IH</sub>	Guaranteed Input High Voltage(2)		2.2	-	6.0	٧
IL	Input Leakage Current	V <sub>CC</sub> = Max, V <sub>IN</sub> = 0V to V <sub>CC</sub>	-2	-	2	μА
loL	Output Leakage Current	$V_{CC} = Max$ , $\overline{E} = V_{IH}$ or $\overline{G} = V_{IH}$ , $V_{IN} = 0V$ to $V_{CC}$	-2	-	2	μА
V <sub>OL</sub>	Output Low Voltage	V <sub>CC</sub> = Min, I <sub>OL</sub> = 8mA	-	-	0.4	٧
V <sub>OH</sub>	Output High Voltage	V <sub>CC</sub> = Min, I <sub>OH</sub> = -4mA	2.4	-	-	٧
Icc	Operating Power Supply Current	$V_{CC} = Max$ , $\overline{E} = V_{IL}$ , $I_{DQ} = 0mA$ , $F = F_{max}^{(4)}$	-	-	180	mA
I <sub>CCSB</sub>	Standby Power Supply Current	V <sub>CC</sub> = Max, E = V <sub>IH</sub> , I <sub>DQ</sub> = 0mA	-	-	35	mA
I <sub>CCSB1</sub>	Power Down Power Supply	$V_{CC} = Max, \overline{E} \ge V_{CC} - 0.2V$	-	-	10	mA
	Current	$V_{IN} \ge V_{CC} - 0.2V$ or $V_{IN} \le 0.2V$				

- Typical characteristics are at  $V_{CC} = 5V$ ,  $T_A = 25^{\circ}C$ . These are absolute values with respect to device ground and all overshoots due to system or tester noise are included.
- $V_{IL}$  (Min.) = -3.0V for pulse width  $\leq$  20ns
- $F_{MAX} = 1/t_{RC.}$

# Capacitance(1) T<sub>A</sub> = 25°C, f = 1.0MHz

Symbol	Parameter	Conditions	Max.	Unit
C IN	Input Capacitance	V <sub>IN</sub> = 0V	8	pF
CIVO	Input/Output Capacitance	V <sub>I/O</sub> = 0V	10	pF

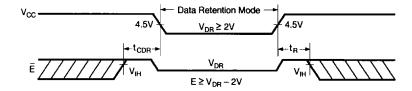
<sup>1.</sup> This parameter is guaranteed and not tested.

# Data Retention Characteristics (over the commercial operating range)

Symbol	Parameter	Test Conditions	Min.	Typ.(1)	Max <sup>(2)</sup>	Units
V <sub>DR</sub>	V <sub>CC</sub> for Data Retention	$E \ge V_{CC} - 0.2V$ , $V_{IN} \ge V_{CC} - 0.2V$ or $V_{IN} \le 0.2V$	2.0(4)	-	-	٧
ICCDR	Data Retention Current	$\overline{E} \ge V_{CC} - 0.2V$ , $V_{IN} \ge V_{CC} - 0.2V$ or $V_{IN} \le 0.2V$	-	2	50	μА
t <sub>CDR</sub>	Chip Deselect to Data Retention Time	See Retention Waveform	0	-	-	ns
t <sub>R</sub>	Operation Recovery Time		t <sub>RC</sub> (3)	-	-	ns

- V<sub>CC</sub> = 2V, T<sub>A</sub> = +25°C V<sub>CC</sub> = 3V
- 2.
- t<sub>RC</sub> = Read Cycle Time

# Timing Waveform Low V<sub>CC</sub> Data Retention Waveform



# MOSEL-VITELIC MS62256A

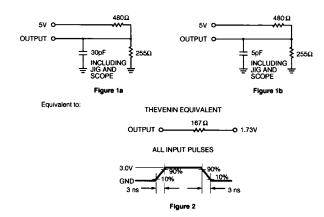
#### **AC Test Conditions**

Input Pulse Levels	0V to 3.0V
Input Rise and Fall Times	3ns
Timing Reference Level	1.5V

# Key to Switching Waveforms

WAVEFORM	INPUTS	OUTPUTS
	MUST BE STEADY	WILL BE STEADY
IIII	MAY CHANGE FROM H TO L	WILL BE CHANGING FROM H TO L
	MAY CHANGE FROM L TO H	WILL BE CHANGING FROM L TO H
XXX	DON'T CARE: ANY CHANGE PERMITTED	CHANGING: STATE UNKNOWN
<b>&gt;</b> «	DOES NOT APPLY	CENTER LINE IS HIGH IMPEDANCE "OFF" STATE

#### AC Test Loads and Waveforms



# AC Electrical Characteristics (over the commercial operating range)

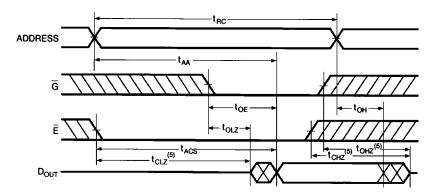
# Read Cycle

Jedec			MS62	256A-20	MS62	256A-25	MS62	256A-35	
Parameter Name	Parameter Name	Parameter	Min.	Max.	Min.	Max.	Min.	Max.	Unit
t <sub>AVAX</sub>	t <sub>RC</sub>	Read Cycle Time	20	<del>-</del>	25	-	35	-	ns
t <sub>AVQV</sub>	t <sub>AA</sub>	Address Access Time	-	20	-	25	-	35	ns
t <sub>ELQV</sub>	t <sub>ACS</sub>	Chip Enable Access Time	-	20	-	25	-	35	ns
t <sub>GLOX</sub>	t <sub>OE</sub>	Output Enable to Output Valid	-	8	-	12	-	15	ns
t <sub>EHQZ</sub>	t <sub>CLZ</sub>	Chip Enable to Output Low Z	3	-	5	-	5	_	ns
t <sub>GLOX</sub>	toLZ	Output Enable to Output in Low Z	0		0	-	0	-	ns
t <sub>EHOZ</sub>	t <sub>CHZ</sub>	Chip Disable to Output in High Z		. 8	-	10	-	15	ns
t <sub>GHQZ</sub>	t <sub>OHZ</sub>	Output Disable to Output in High Z		7	-	10	-	15	ns
t <sub>AXQX</sub>	t <sub>OH</sub>	Output Hold from Address Change	3		5	-	5	-	ns

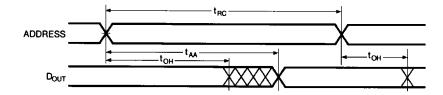
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# Switching Waveforms (Read Cycle)

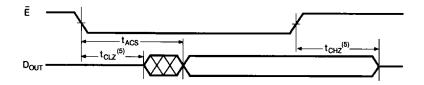
## **READ CYCLE 1<sup>(1)</sup>**



#### **READ CYCLE 2<sup>(1, 2, 4)</sup>**



#### **READ CYCLE 3(1, 3, 4)**



#### NOTES:

- W is High for READ Cycle.
- Device is continuously selected  $\overline{E} = V_{IL}$ . Address valid prior to or coincident with  $\overline{E}$  transition low. 3.
- 4.
- Transition is measured  $\pm$  500mV from steady state with  $C_L = 5pF$  as shown in Figure 1b. This parameter is guaranteed and not 100% tested.

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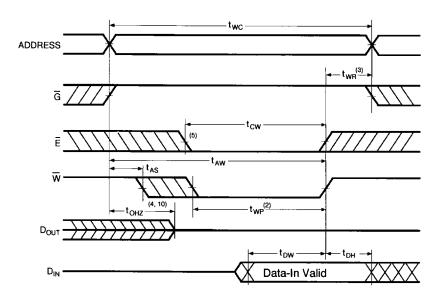
# AC Electrical Characteristics (over the commercial operating range)

# Write Cycle

Jedec		· · · · · · · · · · · · · · · · · · ·	MS	2256A-20	MS62	256A-25	MS62	256A-35	
Parameter Name	Parameter Name	Parameter	Min	Max.	Min.	Max.	Min.	Max.	Unit
t <sub>AVAX</sub>	t <sub>WC</sub>	Write Cycle Time	20	-	25	-	35	-	ns
t <sub>ELWH</sub>	t <sub>cw</sub>	Chip Enable to End of Write	15		20	-	25	-	ns
t <sub>AVWL</sub>	t <sub>AS</sub>	Address Set up Time	0	-	0	-	0	-	ns
t <sub>AVWH</sub>	t <sub>AW</sub>	Address Valid to End of Write	15	-	20	-	25	-	ns
t <sub>WLWH</sub>	t <sub>WP</sub>	Write Pulse Width	15	-	15		20	-	ns
t <sub>WHAX</sub>	t <sub>WR</sub>	Write Recovery Time	0	+	0	-	0	-	ns
twLoz	t <sub>WHZ</sub>	Write to Output in High Z	0	8	0	13	0	15	ns
t <sub>DVWH</sub>	t <sub>DW</sub>	Data to Write Time Overlap	10	-	13	-	15	-	ns
t <sub>WHDX</sub>	t <sub>DH</sub>	Data Hold from Write Time	0	-	0	-	0	-	ns

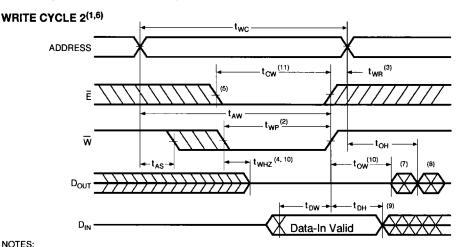
# Switching Waveforms (Write Cycle)

# WRITE CYCLE 1(1)



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## Switching Waveforms (Write Cycle)



#### NOTES:

- W must be high during address transitions. 1.
- The internal write time of the memory is defined by the overlap  $\overline{E}$  active and  $\overline{W}$  low. Both signals must be active to initiate and any one signal can terminate a write by going inactive. The data input setup and hold timing should be referenced to the second transition edge of the signal that terminates the write.
- 3.  $T_{WR}$  is measured from the earlier of  $\overline{E}$  or  $\overline{W}$  going high at the end of write cycle.
- During this period, DQ pins are in the output state so that the input signals of opposite phase to the outputs must not be applied.
- 5. If the E low transition occurs simultaneously with the  $\overline{W}$  low transitions or after the  $\overline{W}$  low transition, outputs remain in a high impedance state.
- 6.  $\overline{G}$  is continuously low ( $\overline{G} = V_{IL}$ ).
- 7. D<sub>OUT</sub> is the same phase of write data of this write cycle.
- D<sub>QUT</sub> is the read data of next address.
- If E is low during this period, DQ pins are in the output state. Then the data input signals of opposite phase to the outputs must not be applied to them.
- 10. Transition is measured ±500mV from steady state with C<sub>L</sub> = 5pF as shown in Figure 1b on page 4. This parameter is guaranteed and not 100% tested.
- 11.  $t_{CW}$  is measured from  $\overline{E}$  going low to the end of write.

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# Ordering Information

Speeds	Ordering Part Number	Package	Temperature Range
20	MS62256A-20NC	28 Pin Plastic DIP - 300 mil	0°C to +70°C
20	MS62256A-20RC	28 Pin Small Outline J Bend	0°C to +70°C
25	MS62256A-25NC	28 Pin Plastic DIP - 300 mil	0°C to +70°C
25	MS62256A-25RC	28 Pin Small Outline J Bend	0°C to +70°C
35	MS62256A-35NC	28 Pin Plastic DIP - 300 mil	0°C to +70°C
35	MS62256A-35RC	28 Pin Small Outline J Bend	0°C to +70°C